

Anisotropic Electronic Correlations in the Spin Density Wave State of $\text{La}_3\text{Ni}_2\text{O}_7$

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22 **A. Raman selection rules and Raman-active phonons**

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24 La₃Ni₂O₇ at ambient pressure belongs to space group *Amam* with *D*_{2h} point group [1]. The
 25 factor group symmetry analysis indicates that the Raman phonon modes at Brillouin zone (BZ)
 26 center Γ should be decomposed into 36 irreducible representations, $\Gamma_{Raman} = 10A_g + 12B_{1g} +$
 27 $7B_{2g} + 7B_{3g}$. We adopted the lattice parameters $a = 5.450$ Å, $b = 5.398$ Å, $c = 20.561$ Å, and
 28 the Wyckoff positions (La1 4c, La2 8g, Ni 8g, O1 8e, O2 8e, O3 8g and O4 4c) [2]. The Raman
 29 tensors R_μ ($\mu = A_g, B_{1g}, B_{2g}, B_{3g}$) corresponding to the symmetry group are expressed in the *xyz*
 30 coordinates as:

$$A_g = \begin{pmatrix} a & 0 & 0 \\ 0 & b & 0 \\ 0 & 0 & c \end{pmatrix}, B_{1g} = \begin{pmatrix} 0 & d & 0 \\ d & 0 & 0 \\ 0 & 0 & 0 \end{pmatrix}, \quad (1)$$

$$B_{2g} = \begin{pmatrix} 0 & 0 & e \\ 0 & 0 & 0 \\ e & 0 & 0 \end{pmatrix}, B_{3g} = \begin{pmatrix} 0 & 0 & 0 \\ 0 & 0 & f \\ 0 & f & 0 \end{pmatrix}.$$

31 The Raman scattering intensity can be deduced as:

$$I \propto |e_i \cdot R_\mu \cdot e_s|^2. \quad (2)$$

32 where e_i and e_s are the unit polarization vectors of the incident and scattered light, respectively.
 33 According to the polarization selection rules, the peaks appearing under (*xx* and *x'x'*) configura-
 34 tions are A_g modes, while the peaks appearing under (*xy*) polarization configuration should be
 35 B_{1g} modes. The electronic Raman response is analyzed within the *D*_{4h} point group, under which
 36 the B_{1g} phonon modes of the *D*_{2h} crystal symmetry appear in the B_{2g} channel. This convention
 37 is adopted for consistency with the pseudo-tetragonal symmetry of the electronic structure.

38 To perform a quantitative analysis of the phonons, we utilize Voigt functions to fit these peaks,
 39 which is a convolution of a Guassian and a Lorenz function. The temperature dependent phonon
 40 linewidth is simulated with an anharmonic symmetric decay model [3],

$$\Gamma_i(T) = \Gamma_{i,0} \left[1 + \frac{2\lambda_{i,\text{ph-ph}}}{\exp\left(\frac{\hbar\omega_0}{2k_B T}\right) - 1} \right] \quad (3)$$

41 where $\lambda_{i,\text{ph-ph}}$ is the phonon-phonon coupling constant, and ω_0 is the corresponding phonon fre-
 42 quency at zero temperature.

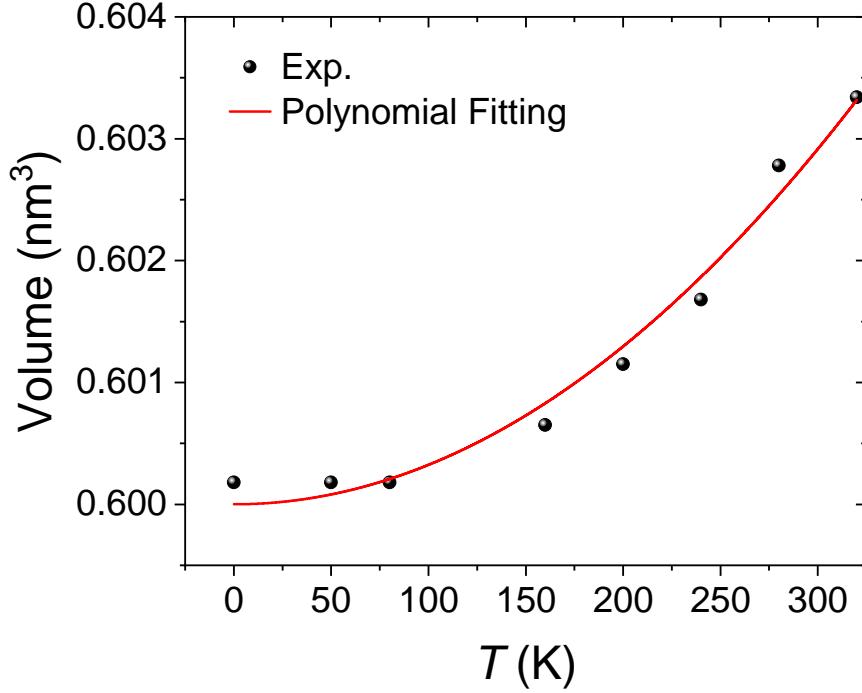


Figure S1. Temperature dependent volume of $\text{La}_3\text{Ni}_2\text{O}_7$. The data are adapted from Ref. [5].

43 The phonon energy shift depends on both the anharmonic decay and the thermal expansion.
 44 With taking both into account, the temperature dependence of the phonon energy $\omega_i(T)$ can be
 45 given by [4]:

$$\omega_i(T) = \omega_{i,0} + \omega_{i,0} \left\{ \exp \left[-3\gamma_i \int_0^T \alpha_V(T') dT' \right] - 1 - \left(\frac{\Gamma_{i,0}}{\sqrt{2}\omega_{i,0}} \right)^2 \left[1 + \frac{4\lambda_{i,\text{ph-ph}}}{\exp \left(\frac{\hbar\omega_{i,0}}{2k_B T} \right) - 1} \right] \right\} \quad (4)$$

46 where γ_i is the Grüneisen parameter of the mode i , and $\alpha_V(T')$ is the coefficient of volume thermal
 47 expansion at temperature T' . The volume thermal expansion of $\text{La}_3\text{Ni}_2\text{O}_7$ are plotted in Fig. S1,
 48 which adopt from Supplementary Materials of Ref. [5].

49 Figure S2 presents the Raman spectra and the corresponding fitting parameters for the A_g and
 50 B_{1g} phonons as a function of temperature. Our analysis focuses on the prominent Raman-active
 51 phonons, namely, the $A_g^{(1)}$, $A_g^{(2)}$, and $B_{1g}^{(3)}$ modes. As shown in Fig. S2 a and b, these phonon modes
 52 are well described by the Voigt function. The extracted phonon frequencies and linewidths as a
 53 function of temperature are plotted in Fig. S2 c and d. The observed temperature dependence
 54 can be explained well by thermal expansion within the framework of Grüneisen theory and by
 55 anharmonic decay, respectively (see green and red lines in Fig. S2 c and d).

56 The absence of any observable phonon anomalies argues against the CDW order as the leading
 57 instability in $\text{La}_3\text{Ni}_2\text{O}_7$. Usually, a CDW transition is typically accompanied by periodic lattice

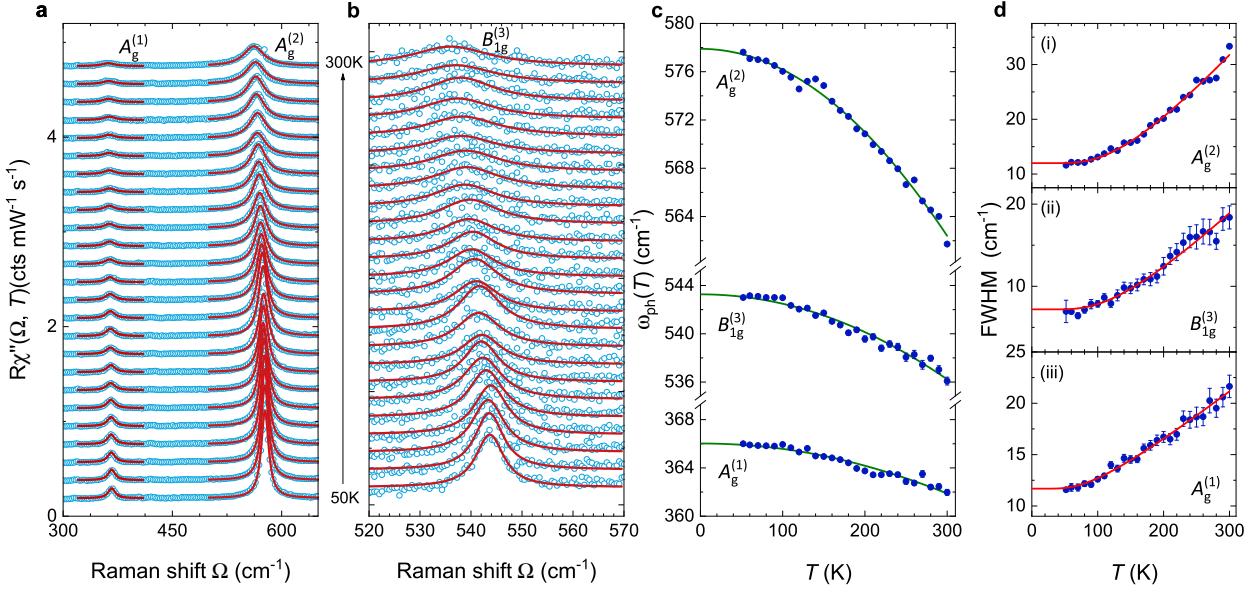


Figure S2. **Raman-active phonons in both the A_g and B_{1g} symmetries.** **a** and **b** Raman response at temperatures ranging from 50 K to 300 K. The spectra other than the one at 50 K are consecutively offset by 0.19 $\text{cts s}^{-1} \text{ mW}^{-1}$ for clarity. The opened blue circles are experimental data. The red curves are Voigt fits. **c** and **d** The plots of phonon energies ω_{ph} and line widths (FWHM) of the three lines as a function of temperature. The green lines in **c** are derived from the volume expansion using Grüneisen theory. The phonon line widths are fitted using an anharmonic model (red lines in **d**). The zero temperature phonon frequency ω_i^0 , Grüneisen parameter γ_i , zero-temperature linewidth Γ_i^0 , and phonon-phonon coupling constant $\lambda_{i,\text{ph-ph}}$ are listed in Tab. I.

Table I. **Phonon parameters of $\text{La}_3\text{Ni}_2\text{O}_7$.** The phonon frequencies ω_i^0 , linewidths Γ_i^0 , the phonon-phonon coupling parameters $\lambda_{i,\text{ph-ph}}$ and the Grüneisen constants γ_i of the Raman-active $A_g^{(1)}$, $B_{1g}^{(3)}$, and $A_g^{(2)}$ phonons are obtained from the fittings.

| Phonons | $\omega_i^0(\text{cm}^{-1})$ | $\Gamma_i^0(\text{cm}^{-1})$ | $\lambda_{i,\text{ph-ph}}$ | γ_i |
|----------------|------------------------------|------------------------------|----------------------------|------------|
| $A_g^{(1)}$ | 366.0 | 11.7 | 0.57 | 0.74 |
| $B_{1g}^{(3)}$ | 543.3 | 7.2 | 2.18 | 0.88 |
| $A_g^{(2)}$ | 578.0 | 11.9 | 2.4 | 1.84 |

58 reconstruction [6, 7], leading to phonon anomalies at the transition temperature and the appearance
 59 of multiple zone-folded phonon modes in the Raman spectra below the transition temperature [8–
 60 10]. Moreover, the CDW amplitude mode, commonly observed in typical CDW materials such as
 61 2H-NbSe₂ [11], ErTe₃ [12], and CsV₃Sb₅ [10], is also not detected in $\text{La}_3\text{Ni}_2\text{O}_7$.

62 **B. Extraction of pure A_{1g} Raman response**

63 To isolate the pure A_{1g} Raman response, we performed polarization-resolved measurements
 64 in multiple scattering geometries and utilized the symmetry decomposition based on the pseudo-
 65 tetragonal D_{4h} point group. Specifically, the A_{1g} component was extracted by combining spectra
 66 from parallel polarizations [$xx(A_{1g} + B_{1g})$ and $x'x'(A_{1g} + B_{2g})$] and subtracting contributions from
 67 cross polarizations [$xy(B_{2g})$ and $x'y'(B_{1g})$], assuming negligible mixing due to sample misalignment
 68 or optical leakage.

69 The extraction procedure follows:

$$\chi''_{A_{1g}}(\Omega) = \chi''_{xx}(\Omega) + \chi''_{x'x'}(\Omega) - \chi''_{xy}(\Omega) - \chi''_{x'y'}(\Omega), \quad (5)$$

70 where $\chi''_{ij}(\Omega)$ denotes the Raman response measured in the $i-j$ polarization configuration. This
 71 approach effectively removes the B_{1g} and B_{2g} components, isolating the A_{1g} contribution under
 72 the assumption of ideal symmetry and linear superposition.

73

74 **C. The temperature-dependent electronic Raman response in $\text{La}_3\text{Ni}_2\text{O}_7$**

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76 To study the evolution of the gap closing with increasing temperature, we present the temper-
 77 ature dependence of Raman spectra and difference spectra [$\Delta\chi''(\Omega, T) = \chi''(\Omega, T) - \chi''(\Omega, 160 \text{ K})$]
 78 in both the B_{1g} and B_{2g} symmetries, as shown in Fig. S3. The redistribution of the spectral weight
 79 gradually decreases and completely disappears at approximately 150 K, indicating that the SDW
 80 gap fully closes above this temperature.

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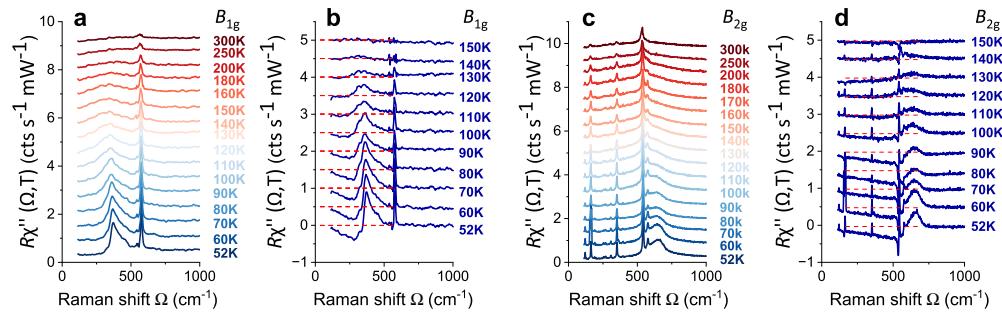


Figure S3. **Electronic Raman spectra in B_{1g} and B_{2g} symmetries.** **a** and **c** Temperature-dependent Raman spectra in the B_{1g} and B_{2g} symmetries at selected temperatures. **b** and **d**, Corresponding difference spectra using the 160 K spectrum as the reference for B_{1g} and B_{2g} symmetries, respectively. Red dashed lines mark the zero-intensity baselines. All spectra are vertically offset for clarity.

82 **D. The fitting results of the electronic Raman response in $\text{La}_3\text{Ni}_2\text{O}_7$**

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84 The Raman spectra in B_{1g} and B_{2g} symmetries are fitted using phenomenological models com-
 85 bining Drude and Tsuneto-Maki or Lorentz functions, respectively (see Fig. S4 and Fig. S5).
 86 These models successfully capture the redistribution of spectral weight below the SDW transition
 87 temperature near 150 K. The B_{1g} channel shows an asymmetric lineshape best described by the
 88 Tsuneto-Maki function, indicating a weak-coupling SDW gap at the β' pocket, while the B_{2g} chan-
 89 nel exhibits a more symmetric response, fitted with a Lorentz profile consistent with a stronger
 90 SDW gap at the β pocket.

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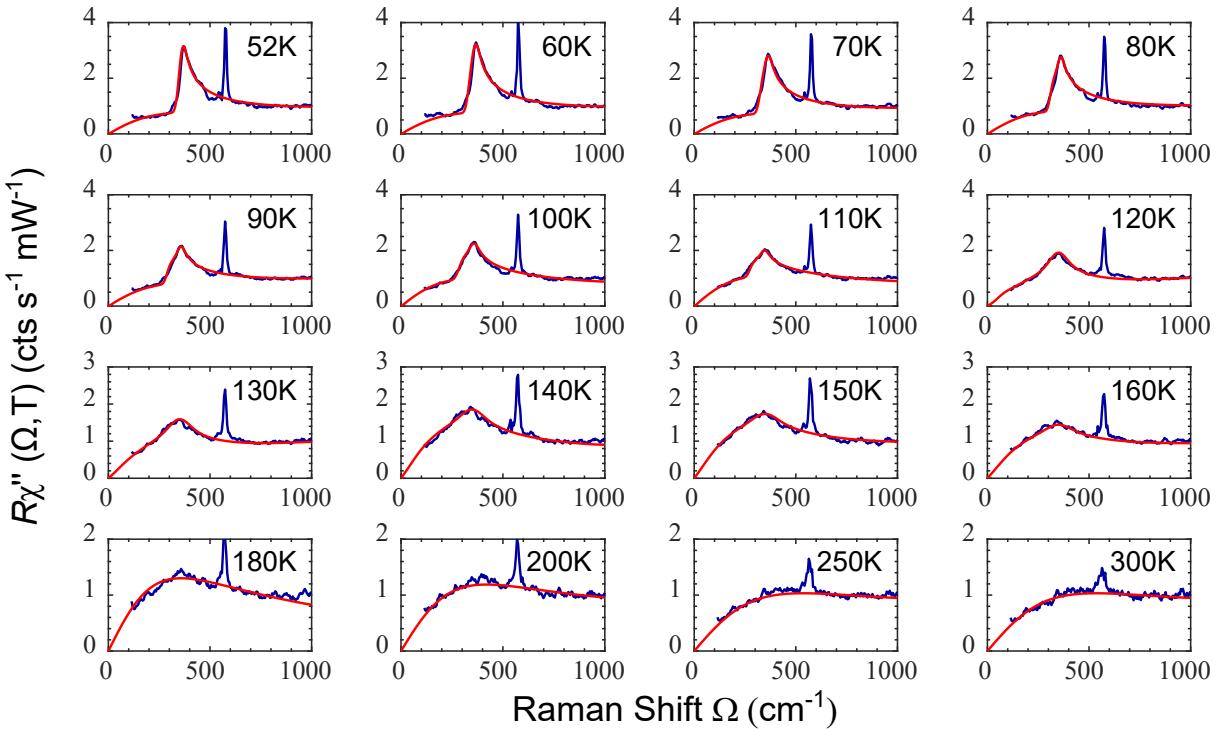


Figure S4. **Fit of the electronic Raman spectra in B_{1g} symmetry.** Raman spectra at various temperatures are fitted using a combined Drude and Tsuneto-Maki model, capturing both the broad background and the asymmetric peak associated with the SDW gap. The experimental data are shown as red lines, while the total fit is overlaid in blue.

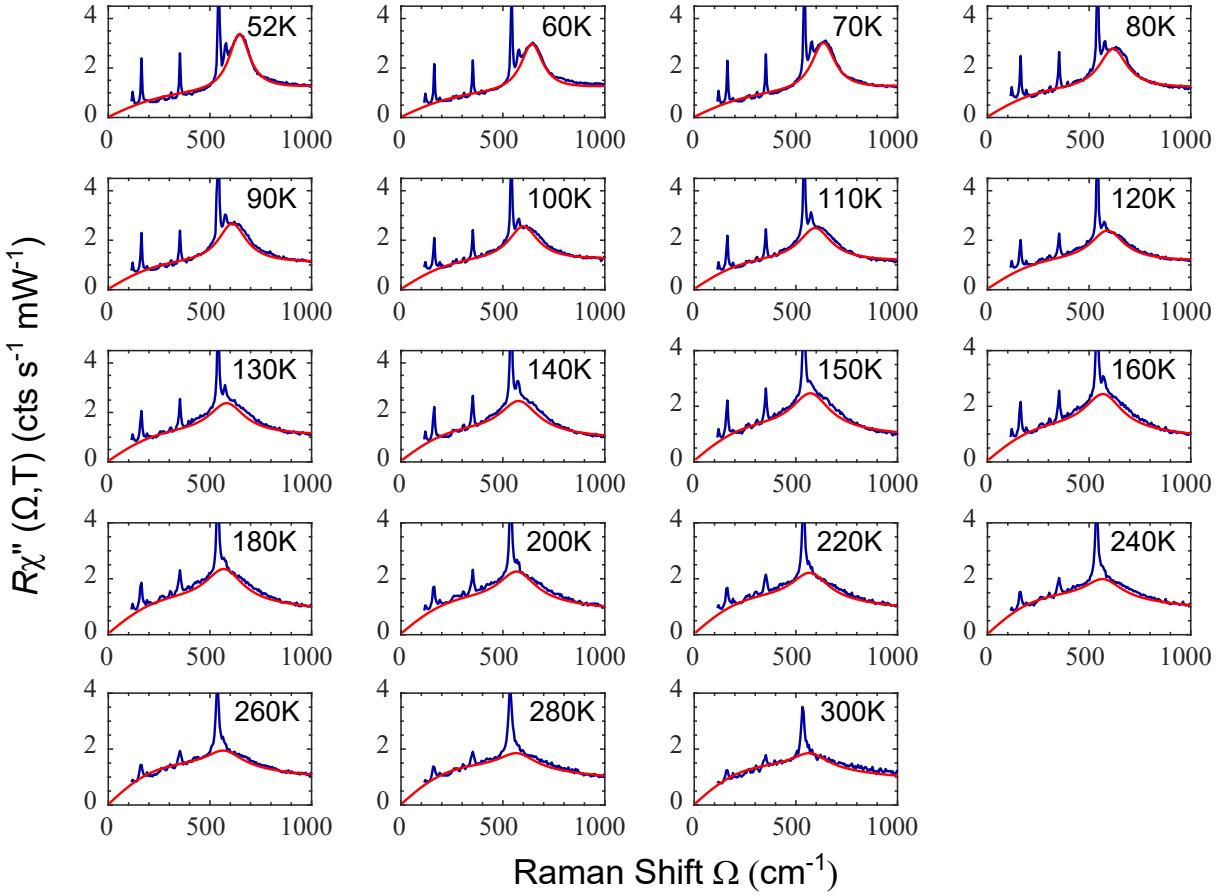


Figure S5. **Fit of the electronic Raman spectra in B_{2g} symmetry.** Raman spectra at various temperatures are fitted using a combined Drude and Lorentz model, capturing both the broad background and the nearly symmetric peak.

92 **E. Tight-binding band structure**

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94 The band structure presented in the main text is calculated using an 8-band tight-binding model
 95 adopted from Ref. [13]. This model accounts for electron hopping within the two Ni-O layers, where
 96 each layer contains two Ni atoms. Each Ni atom contributes two orbitals, namely $d_{x^2-y^2}$ and d_{z^2} .

97 The Hamitonion can be described in the basis $(d_x^{At} \ d_z^{At} \ d_x^{Bt} \ d_z^{Bt} \ d_x^{Ab} \ d_z^{Ab} \ d_x^{Bb} \ d_z^{Bb})$ as:

$$\hat{H} = \begin{pmatrix} H_{11}(\mathbf{k}) & 0 & H_{13}(\mathbf{k}) & (H_{14}(\mathbf{k}) & t_{\perp}^x & 0 & 0 & H_{18}(\mathbf{k}) \\ 0 & H_{22}(\mathbf{k}) & H_{14}(\mathbf{k}) & H_{24}(\mathbf{k}) & 0 & t_{\perp}^z & H_{18}(\mathbf{k}) & 0 \\ H_{13}^*(\mathbf{k}) & H_{14}^*(\mathbf{k}) & H_{11}(\mathbf{k}) & 0 & 0 & H_{18}^*(\mathbf{k}) & t_{\perp}^x & 0 \\ H_{14}^*(\mathbf{k}) & H_{24}^*(\mathbf{k}) & 0 & H_{22}(\mathbf{k}) & H_{18}^*(\mathbf{k}) & 0 & 0 & t_{\perp}^z \\ t_{\perp}^x & 0 & 0 & H_{18}^*(\mathbf{k}) & H_{11}(\mathbf{k}) & 0 & H_{13}(\mathbf{k}) & H_{14}(\mathbf{k}) \\ 0 & t_{\perp}^z & H_{18}^*(\mathbf{k}) & 0 & 0 & H_{22}(\mathbf{k}) & H_{14}(\mathbf{k}) & H_{24}(\mathbf{k}) \\ 0 & H_{18}(\mathbf{k}) & t_{\perp}^x & 0 & H_{13}^*(\mathbf{k}) & H_{14}^*(\mathbf{k}) & H_{11}(\mathbf{k}) & 0 \\ H_{18}(\mathbf{k}) & 0 & 0 & t_{\perp}^z & H_{14}^*(\mathbf{k}) & H_{24}^*(\mathbf{k}) & 0 & H_{22}(\mathbf{k}) \end{pmatrix} \quad (6)$$

98 with $H_{11/22}(\mathbf{k}) = \epsilon^{x/z} + 2(t_2^{x/z} \cos k_X + t_2^{x/z} \cos k_Y) + 4t_5^{x/z} \cos k_X \cos k_Y$, $H_{13/24}(\mathbf{k}) = 2 \cos \frac{1}{2}k_X$
99 $(t_1^{x/z} e^{i\frac{1}{2}k_Y} + t_1^{x/z} e^{-i\frac{1}{2}k_Y})$ and $H_{14/18}(\mathbf{k}) = 2i \sin \frac{1}{2}k_X (t_{3/4}^{xz} e^{i\frac{1}{2}k_Y} - t_{3/4}^{xz} e^{-i\frac{1}{2}k_Y})$, where k_X and
100 k_Y are defined as $k_X = k_x + k_y$ and $k_Y = -k_x + k_y$. Here, A and B label the two Ni atoms
101 occupying in the same layer. t and b indicate the top and bottom layer, respectively. x and z stand
102 for the $d_{x^2-y^2}$ and d_{z^2} orbitals. The band dispersion is given by diagonalizing the Hamitonion as,

$$E_n(\mathbf{k}) = U_n(\mathbf{k}) \hat{H} U_n^*(\mathbf{k}) \quad (7)$$

103 where $U_n(\mathbf{k})$ is the normalized eigen vector.

104 Figure S6 shows the reproduced band structure as reported in Ref. [13]. Among these, Band
105 3 and Band 4 cross the Fermi level and form the hole pockets centered at the X_1 points and the
106 electron pockets centered at the Γ , X , Y , and M points, respectively (see Fig. S7).

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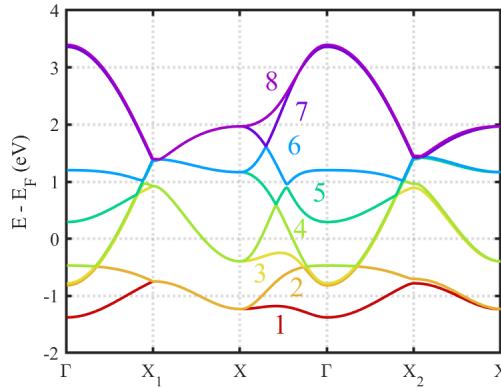


Figure S6. **Band structure along high-symmetric paths calculated using a tight-binding model.**

The band indices are labeled in the figure. Band 3 and band 4 cross the Fermi level.

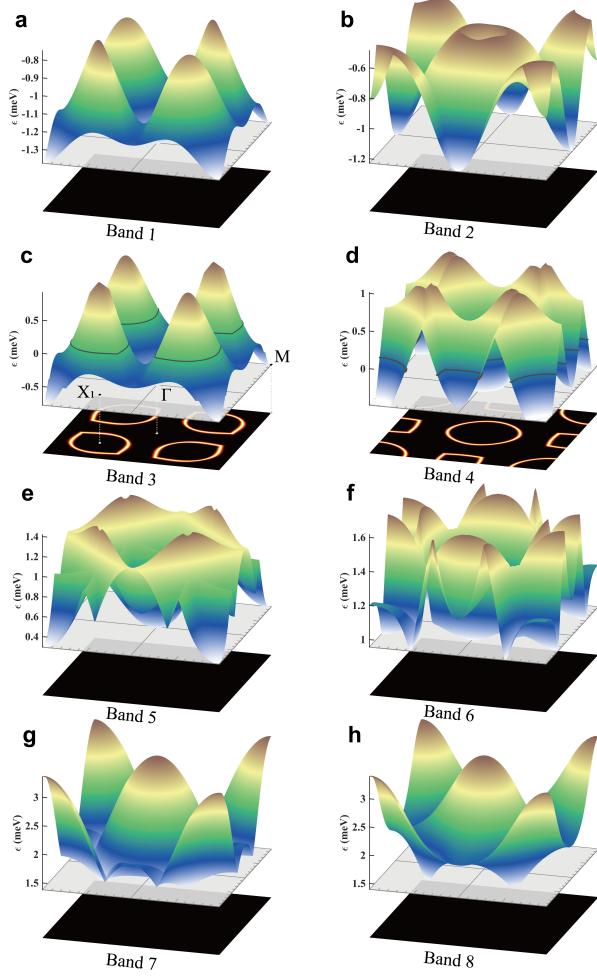


Figure S7. **Band dispersion in 3D view.** The bands are projected onto the Fermi-energy plane. The resulting Fermi pockets are highlighted in panels **c** and **d**.

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112 [1] H. Sun, M. Huo, X. Hu, J. Li, Z. Liu, Y. Han, L. Tang, Z. Mao, P. Yang, B. Wang, J. Cheng, D.-X.
113 Yao, G.-M. Zhang, and M. Wang, Signatures of superconductivity near 80 K in a nickelate under high
114 pressure, *Nature* **621**, 493 (2023).

115 [2] Y. Meng, Y. Yang, H. Sun, S. Zhang, J. Luo, L. Chen, X. Ma, M. Wang, F. Hong, X. Wang, and
116 X. Yu, Density-wave-like gap evolution in $\text{La}_3\text{Ni}_2\text{O}_7$ under high pressure revealed by ultrafast optical
117 spectroscopy, *Nat. Commun.* **15**, 10408 (2024).

118 [3] P. G. Klemens, Anharmonic decay of optical phonons, *Phys. Rev.* **148**, 845 (1966).

119 [4] H. Eiter, P. Jaschke, R. Hackl, A. Bauer, M. Gangl, and C. Pfleiderer, Raman study of the temperature
120 and magnetic-field dependence of the electronic and lattice properties of mnsi, *Phys. Rev. B* **90**, 024411
121 (2014).

122 [5] H. Wang, H. Zhou, and W. Xie, Temperature-dependent structural evolution of ruddlesden–popper
123 bilayer nickelate $\text{La}_3\text{Ni}_2\text{O}_7$, *Inorg. Chem.* **64**, 828 (2025).

124 [6] K. Rossnagel, On the origin of charge-density waves in select layered transition-metal dichalcogenides,
125 *J. Phys.: Condens. Matter* **23**, 213001 (2011).

126 [7] G. Grüner, *Density Waves in Solids* (Perseus, Cambridge, MA, 1994).

127 [8] R. Samnakay, D. Wickramaratne, T. R. Pope, R. K. Lake, T. T. Salguero, and A. A. Balandin, Zone-
128 folded phonons and the commensurate–incommensurate charge-density-wave transition in $1T - \text{TaSe}_2$
129 thin films, *Nano Lett.* **15**, 2965 (2015).

130 [9] O. R. Albertini, R. Zhao, R. L. McCann, S. Feng, M. Terrones, J. K. Freericks, J. A. Robinson, and A. Y.
131 Liu, Zone-center phonons of bulk, few-layer, and monolayer $1T - \text{TaS}_2$: Detection of commensurate
132 charge density wave phase through Raman scattering, *Phys. Rev. B* **93**, 214109 (2016).

133 [10] G. He, L. Peis, E. F. Cuddy, Z. Zhao, D. Li, Y. Zhang, R. Stumberger, B. Moritz, H. Yang, H. Gao,
134 T. P. Devreaux, and R. Hackl, Anharmonic strong-coupling effects at the origin of the charge density
135 wave in CsV_3Sb_5 , *Nat. Commun.* **15**, 1895 (2024).

136 [11] M.-A. Méasson, Y. Gallais, M. Cazayous, B. Clair, P. Rodière, L. Cario, and A. Sacuto, Amplitude
137 higgs mode in the $2H - \text{NbSe}_2$ superconductor, *Phys. Rev. B* **89**, 060503 (2014).

138 [12] H.-M. Eiter, M. Lavagnini, R. Hackl, E. A. Nowadnick, A. F. Kemper, T. P. Devreaux, J.-H. Chu,
139 J. G. Analytis, I. R. Fisher, and L. Degiorgi, Alternative route to charge density wave formation in
140 multiband systems, *Proc. Natl. Acad. Sci.* **110**, 64 (2013).

141 [13] Y. Wang, K. Jiang, Z. Wang, F.-C. Zhang, and J. Hu, Electronic and magnetic structures of bilayer
142 $\text{La}_3\text{Ni}_2\text{O}_7$ at ambient pressure, *Phys. Rev. B* **110**, 205122 (2024).